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Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Height:

0.165 inches

Overall Width:

0.205 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-92

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 3.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 nanoamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

310.0 milliwatts small-signal input power, common-collector

Transfer Ratio:

20.0 small-signal short-circuit forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

135.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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